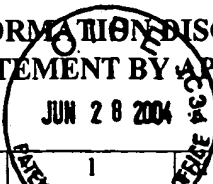


FORM PTO-1449/A and B (Modified)		APPLICATION NO.: 10/635,240	ATTY. DOCKET NO.: M0925.70138US00
<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> 		FILING DATE: August 5, 2003	CONFIRMATION NO.: 9369
		APPLICANT: Yet-Ming Chiang et al.	
Sheet	1	3	EXAMINER: Carol M. Koslow

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		Number	Kind Code		
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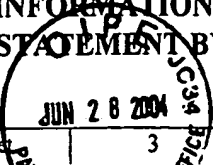
FORM PTO-1449/A and B (Modified)		APPLICATION NO.: 10/635,240	ATTY. DOCKET NO.: M0925.70138US00
<b>INFORMATION NON DISCLOSURE STATEMENT BY APPLICANT</b> JUN 28 2004 PATENT & TRADEMARK OFFICE		FILING DATE: August 5, 2003	CONFIRMATION NO.: 9369
		APPLICANT: Yet-Ming Chiang et al.	
		GROUP ART UNIT: 1755	EXAMINER: Carol M. Koslow
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		Office/Country	Number	Kind Code			
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G		WO	00/41256	A1	Massachusetts Institute of Technology	07-13-2000	Y
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G		WO	03/056646	A1	Massachusetts Institute of Technology	07-10-2003	Y

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Examiner's Initials	Cite No	Include name of the author (in CAPITAL LETTERS) title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, relevant page(s), volume-issue number(s), publisher, city and/or country where published.	Translation (Y/N)
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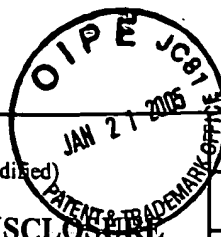
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<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> 		FILING DATE: August 5, 2003	CONFIRMATION NO.: 9369
		APPLICANT: Yet-Ming Chiang et al.	
		GROUP ART UNIT: 1755	EXAMINER: Carol M. Koslow
Sheet	3	of	3

* International Search Report for PCT/US01/11549, filed April 10, 2001			
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EXAMINER 	DATE CONSIDERED 5/10/05
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#EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

\*a copy of this reference is not provided as it was previously cited by or submitted to the office in a prior application, Serial No. 09/174,981, filed October 19, 1998, and relied upon for an earlier filing date under 35 U.S.C. 120 (continuation, continuation-in-part, and divisional applications).



FORM PTO-1449/A and B (Modified)

**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT**

APPLICATION NO.: 10/635,240

ATTY. DOCKET NO.: M0925.70138US00

FILING DATE: August 5, 2003

CONFIRMATION NO.: 9369

APPLICANT: Chiang, et al.

GROUP ART UNIT: 1755

EXAMINER: Carol M. Koslow

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		Number	Kind Code		

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Examiner's Initials	Cite No.	Foreign Patent Document			Name of Patentee or Applicant of Cited Document (not necessary)	Date of Publication of Cited Document MM-DD-YYYY	Translation (Y/N)
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O		R. D. Shannon, "Revised Effective Ionic Radii And Systematic Studies Of Interatomic Distances In Halides And Chalcogenides," Acta Cryst. (1976), A32, pp. 751-767		
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EXAMINE R

DATE CONSIDERED

5/16/05

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[NOTE - The Office hereby waives the requirement under 37 CFR 1.98 (a)(2)(i) for submitting a copy of each cited U.S. patent and each U.S. patent application publication for all U.S. national patent applications filed after June 30, 2003 and for all international applications that have entered the national stage under 35 USC 371 after June 30, 2003. See 37 CFR 1.491(b). For all patent applications filed on or before June 30, 2003, copies of cited U.S. patents and patent application publications are still required unless an IDS is filed. Copies of all other patent(s), publication(s), or other information listed must still be provided, even if it was previously submitted to, or cited by, the U.S. Patent Office in an earlier application, unless the earlier application is identified by the IDS and is relied upon for an earlier filing date under 35 U.S.C. §120, and the copy was provided in the earlier application.]